

THERMAL CHARACTERISTICS

Parameter

TYPICAL CHARACTERISTICS

CAPACITANCE (pF)

V_{GS}, GATE-TO-SOURCE VOLTAGE (V)

I _D = 20 A	V _{DD} = 390 V		V _{DD} = 650 V







ID, DRAIN CURRENT (A)







V_{DS}, DRAIN-TO-SOURCE VOLTAGE (V)

Figure 8. Capacitance vs. Drain-to-Source Voltage



T_C, CASE TEMPERATURE (°C)

Figure 10. Maximum Continuous Drain **Current vs. Case Temperature**



t, PULSE WIDTH (sec)

Figure 12. Single Pulse Maximum Power Dissipation

1 Alera	

H-PSOF8L 9.90x10.38x2.30, 1.20P CASE 100DC ISSUE D

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